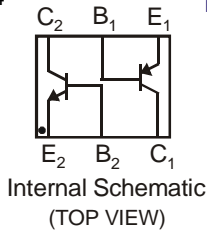


Features

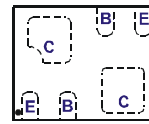
- Complementary Pair: One 3904 (NPN) and One 3906 (PNP)
- Epitaxial Planar Die Construction
- Ideally Suited for Automated Assembly Processes
- Lead Free by Design/RoHS Compliant (Note 1)
- "Green" Device (Note 2)

Mechanical Data

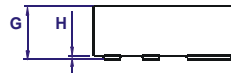
- Case: DFN1310H4-6
- Case Material: Molded Plastic. "Green Molding" Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Finish – NiPdAu over Copper leadframe (Lead Free Plating) Solderable per MIL-STD-202, Method 208
- Marking & Type Code Information: See Page 4
- Ordering Information: See Page 4



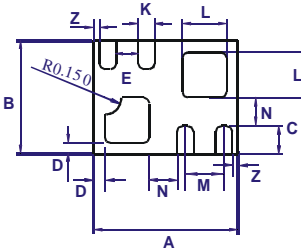
E₁, B₁, C₁ = PNP3906 Section
E₂, B₂, C₂ = NPN3904 Section



Top View



Side View



Bottom View

DFN1310H4-6			
Dim	Min	Max	Typ
A	1.25	1.38	1.30
B	0.95	1.08	1.00
C	0.20	0.30	0.25
D*	-	-	0.10
E**	-	-	0.20
G	-	0.40	-
H	0	0.05	0.02
K*	0.10	0.20	0.15
L*	0.30	0.50	0.40
M**	-	-	0.35
N*	-	-	0.25
Z**	-	-	0.05

All Dimensions in mm

* Dimensions D, K, L, N Repeat 4X
** Dimensions E, M, Z Repeat 2X

Maximum Ratings, NPN 3904 Section @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CB0}	60	V
Collector-Emitter Voltage	V _{CEO}	40	V
Emitter-Base Voltage	V _{EBO}	6.0	V
Collector Current – Continuous	I _c	200	mA
Power Dissipation (Notes 3, 4)	P _d	200	mW
Thermal Resistance, Junction to Ambient (Note 3)	R _{θJA}	625	°C/W

Maximum Ratings, PNP 3906 Section @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CB0}	-40	V
Collector-Emitter Voltage	V _{CEO}	-40	V
Emitter-Base Voltage	V _{EBO}	-5.0	V
Collector Current - Continuous (Note 1)	I _c	-200	mA
Power Dissipation (Notes 3, 4)	P _d	200	mW
Thermal Resistance, Junction to Ambient (Note 3)	R _{θJA}	625	°C/W

- Notes:
1. No purposefully added lead.
 2. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.
 3. Device mounted on FR-4 PCB.
 4. Maximum combined dissipation.

Electrical Characteristics, NPN 3904 Section @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	Min	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 5)					
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	60	—	V	$I_C = 10\mu\text{A}, I_E = 0$
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	40	—	V	$I_C = 1.0\text{mA}, I_B = 0$
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	6.0	—	V	$I_E = 10\mu\text{A}, I_C = 0$
Collector Cutoff Current	I_{CEX}	—	50	nA	$V_{CE} = 30\text{V}, V_{EB(OFF)} = 3.0\text{V}$
Base Cutoff Current	I_{BL}	—	50	nA	$V_{CE} = 30\text{V}, V_{EB(OFF)} = 3.0\text{V}$
ON CHARACTERISTICS (Note 5)					
DC Current Gain	h_{FE}	40	—	—	$I_C = 100\mu\text{A}, V_{CE} = 1.0\text{V}$
		70	—		
		100	300		
		60	—		
		30	—		
Collector-Emitter Saturation Voltage	$V_{CE(SAT)}$	—	0.20 0.30	V	$I_C = 10\text{mA}, I_B = 1.0\text{mA}$ $I_C = 50\text{mA}, I_B = 5.0\text{mA}$
Base-Emitter Saturation Voltage	$V_{BE(SAT)}$	0.65 —	0.85 0.95	V	$I_C = 10\text{mA}, I_B = 1.0\text{mA}$ $I_C = 50\text{mA}, I_B = 5.0\text{mA}$
SMALL SIGNAL CHARACTERISTICS					
Output Capacitance	C_{obo}	—	4.0	pF	$V_{CB} = 5.0\text{V}, f = 1.0\text{MHz}, I_E = 0$
Current Gain-Bandwidth Product	f_T	300	—	MHz	$V_{CE} = 20\text{V}, I_C = 20\text{mA}, f = 100\text{MHz}$
SWITCHING CHARACTERISTICS					
Delay Time	t_d	—	35	ns	$V_{CC} = 3.0\text{V}, I_C = 10\text{mA}$
Rise Time	t_r	—	35	ns	$V_{BE(off)} = -0.5\text{V}, I_{B1} = 1.0\text{mA}$
Storage Time	t_s	—	200	ns	$V_{CC} = 3.0\text{V}, I_C = 10\text{mA}$
Fall Time	t_f	—	50	ns	$I_{B1} = I_{B2} = 1.0\text{mA}$

Electrical Characteristics, PNP 3906 Section @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	Min	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 5)					
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	-40	—	V	$I_C = -10\mu\text{A}, I_E = 0$
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	-40	—	V	$I_C = -1.0\text{mA}, I_B = 0$
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	-5.0	—	V	$I_E = -10\mu\text{A}, I_C = 0$
Collector Cutoff Current	I_{CEX}	—	-50	nA	$V_{CE} = -30\text{V}, V_{EB(OFF)} = -3.0\text{V}$
Base Cutoff Current	I_{BL}	—	-50	nA	$V_{CE} = -30\text{V}, V_{EB(OFF)} = -3.0\text{V}$
ON CHARACTERISTICS (Note 5)					
DC Current Gain	h_{FE}	60	—	—	$I_C = -100\mu\text{A}, V_{CE} = -1.0\text{V}$
		80	—		
		100	300		
		60	—		
		30	—		
Collector-Emitter Saturation Voltage	$V_{CE(SAT)}$	—	-0.25 -0.40	V	$I_C = -10\text{mA}, I_B = -1.0\text{mA}$ $I_C = -50\text{mA}, I_B = -5.0\text{mA}$
Base-Emitter Saturation Voltage	$V_{BE(SAT)}$	-0.65 —	-0.85 -0.95	V	$I_C = -10\text{mA}, I_B = -1.0\text{mA}$ $I_C = -50\text{mA}, I_B = -5.0\text{mA}$
SMALL SIGNAL CHARACTERISTICS					
Output Capacitance	C_{obo}	—	4.5	pF	$V_{CB} = -5.0\text{V}, f = 1.0\text{MHz}, I_E = 0$
Current Gain-Bandwidth Product	f_T	250	—	MHz	$V_{CE} = -20\text{V}, I_C = -10\text{mA}, f = 100\text{MHz}$
SWITCHING CHARACTERISTICS					
Delay Time	t_d	—	35	ns	$V_{CC} = -3.0\text{V}, I_C = -10\text{mA}$
Rise Time	t_r	—	35	ns	$V_{BE(off)} = 0.5\text{V}, I_{B1} = -1.0\text{mA}$
Storage Time	t_s	—	225	ns	$V_{CC} = -3.0\text{V}, I_C = -10\text{mA}$
Fall Time	t_f	—	75	ns	$I_{B1} = I_{B2} = -1.0\text{mA}$

Notes: 5. Short duration test pulse used to minimize self-heating effect.

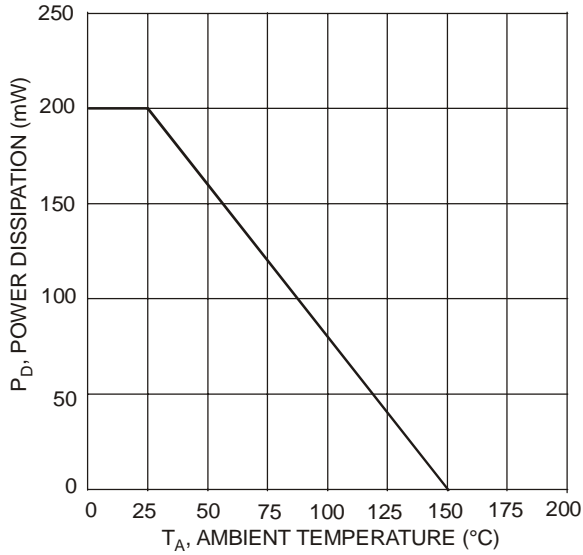


Fig. 1, Max Power Dissipation vs Ambient Temperature (Total Device) (Note 3)

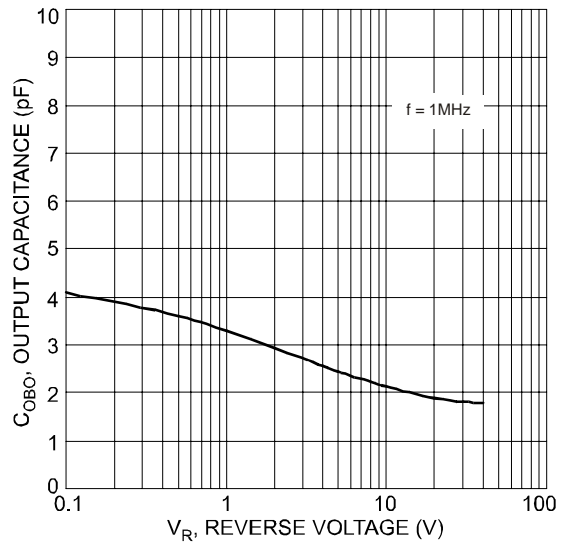


Fig. 2, Typical Output Capacitance Characteristics (NPN-3904)

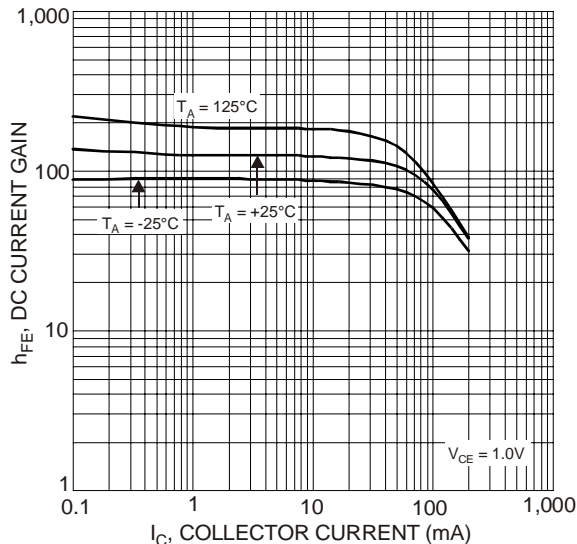


Fig. 3, Typical DC Current Gain vs Collector Current (NPN-3904)

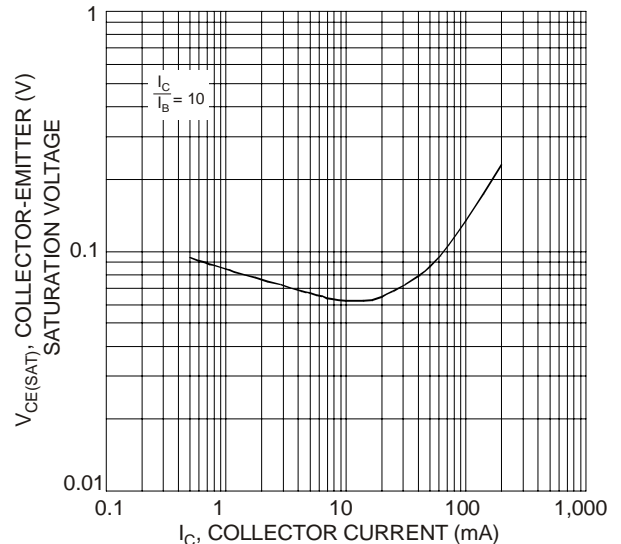


Fig. 4, Typical Collector-Emitter Saturation Voltage vs. Collector Current (NPN-3904)

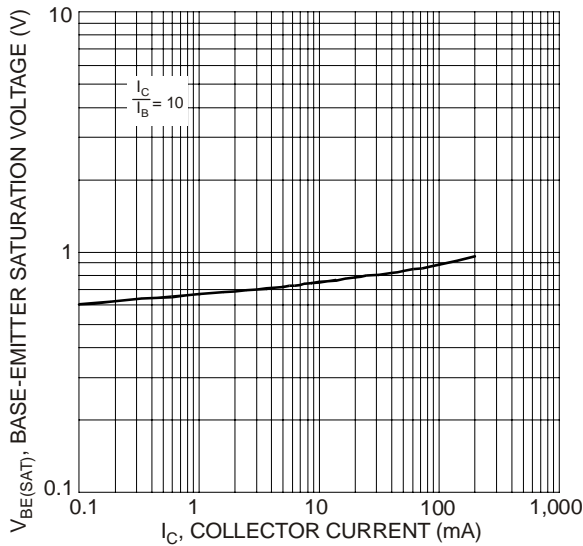


Fig. 5, Typical Base-Emitter Saturation Voltage vs. Collector Current (NPN-3904)

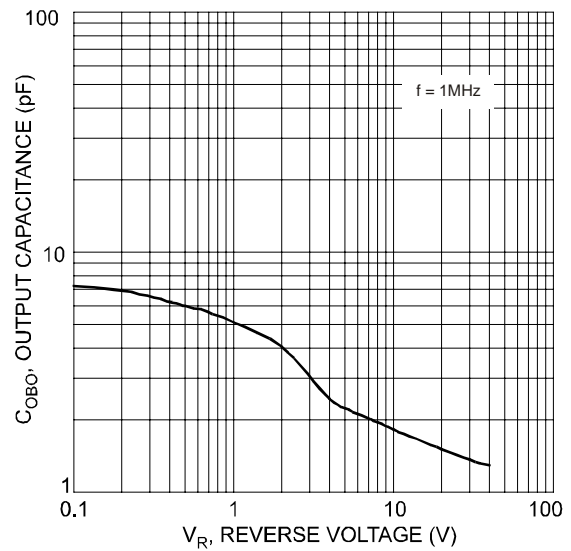


Fig. 6, Typical Output Capacitance Characteristics (PNP-3906)

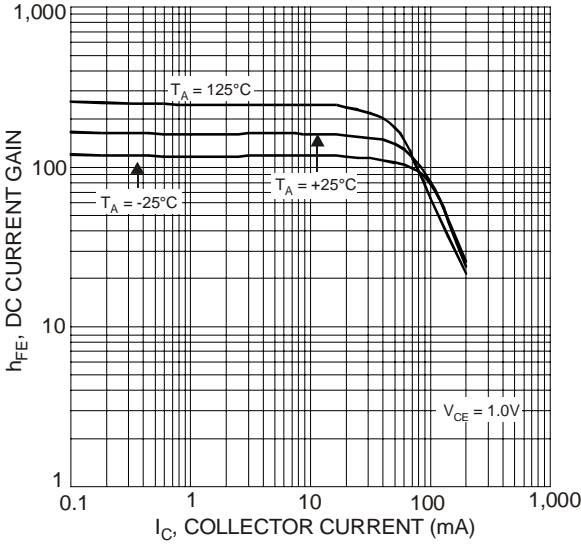


Fig. 7, Typical DC Current Gain vs Collector Current (PNP-3906)

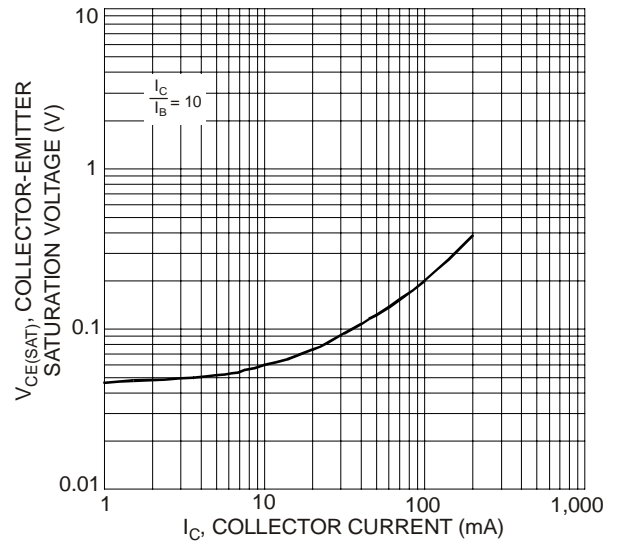


Fig. 8, Typical Collector-Emitter Saturation Voltage vs. Collector Current (PNP-3906)

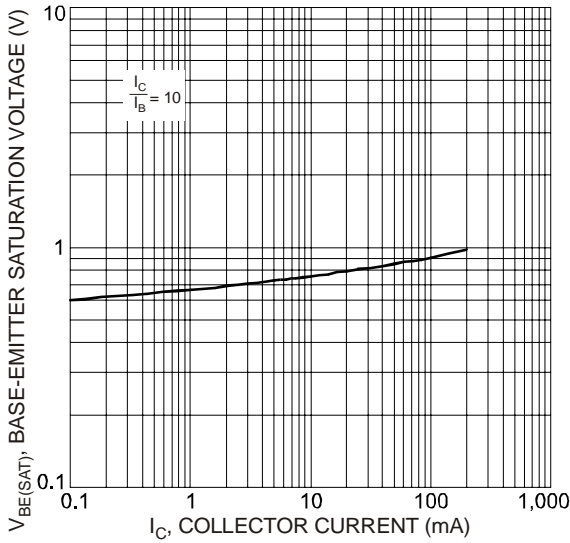


Fig. 9, Typical Base-Emitter Saturation Voltage vs. Collector Current (PNP-3906)

Ordering Information (Note 6)

Device	Packaging	Shipping
MMDT3946LP4-7	DFN1310H4-6	3000/Tape & Reel

Notes: 6. For packaging details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.

Marking Information



46= Product Type Marking Code

IMPORTANT NOTICE

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to any product herein. Diodes Incorporated does not assume any liability arising out of the application or use of any product described herein; neither does it convey any license under its patent rights, nor the rights of others. The user of products in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on our website, harmless against all damages.

LIFE SUPPORT

Diodes Incorporated products are not authorized for use as critical components in life support devices or systems without the expressed written approval of the President of Diodes Incorporated.

单击下面可查看定价，库存，交付和生命周期等信息

[>>Diodes Incorporated\(达达科技\(美台\)\)](#)